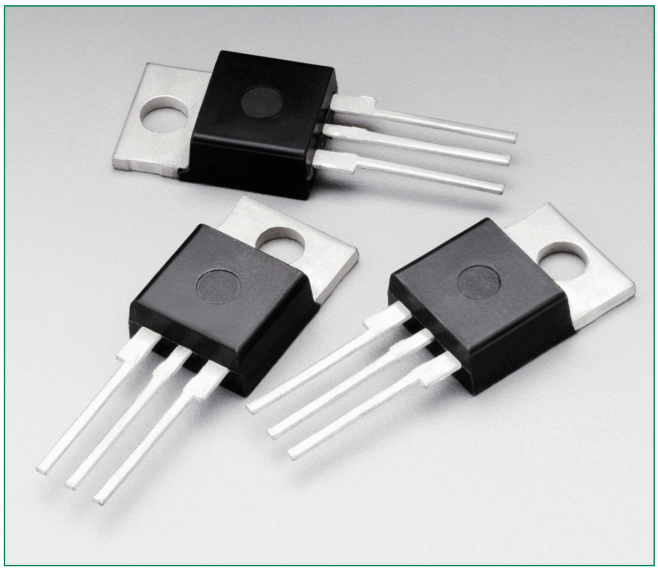
MAC3030-8



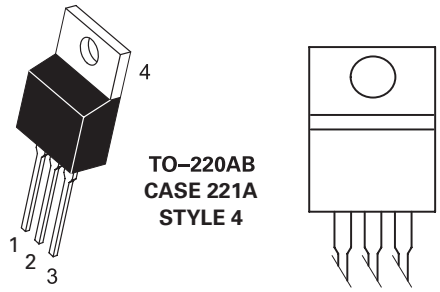
Description

Designed primarily for full-wave AC control applications, such as light dimmers, motor controls, heating controls and power supplies; or wherever full–wave silicon gate controlled solid–state devices are needed. Triac type thyristors switch from a blocking to a conducting state for either polarity of applied main terminal voltage with positive or negative gate triggering.

Features

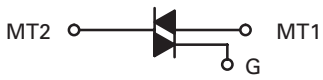
- Blocking Voltage to 250 Volts
- All Diffused and Glass Passivated Junctions for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Construction for Low Thermal Resistance, High Heat Dissipation and Durability
- Gate Triggering Guaranteed in Four Modes (Quadrants)
- Pb–Free Packages are Available

Pin Out



TO–220AB
CASE 221A
STYLE 4

Functional Diagram



Additional Information

Datasheet | **Resources** | **Samples**

Revised: 08/30/17

Maximum Ratings (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off–State Voltage (Note 1) (– 40 to 1125°C, Sine Wave, 50 to 60 Hz, Gate Open)	V_{DRM}, V_{RRM}	250	V
On-State RMS Current (T_C = +70°C) Full Cycle Sine Wave, 50 to 60 Hz	$I_{T\ (RMS)}$	8.0	A
Peak Non-Repetitive Surge Current (One Full Cycle Sine Wave, 60 Hz, T_C = +25°C) Preceded and followed by rated current	I_{TSM}	80	A
Circuit Fusing Consideration (t = 8.3 ms)	I^2t	26	A^2sec
Peak Gate Current, (TC = +70°C, Pulse Width = 10 µs)	I_{GM}	2.0	A
Peak Gate Power (T_C = +70°C, Pulse Width = 10 µs)	P_{GM}	20	W
Average Gate Power (T_C = +70°C, t = 8.3 ms)	$P_{G\ (AV)}$	0.35	W
Operating Junction Temperature Range	T_J	-40 to +125	°C
Storage Temperature Range	T_{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

Thermal Characteristics

Rating		Symbol	Value	Unit
Thermal Resistance,	Junction–to–Case (AC)	R_{8JC}	2.0	°C/W
	Junction–to–Ambient	R_{8JA}	62.5	
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds		T_L	260	°C

Revised: 08/30/17

Electrical Characteristics - OFF (T_J = 25°C unless otherwise noted ; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak Repetitive Blocking Current ($V_D = V_{DRM} = V_{RRM}$; Gate Open)	T_J = 25°C	I_{DRM}, I_{RRM}	-	-	10	µA
	T_J = 125°C		-	-	2.0	mA

Electrical Characteristics - ON (T_J = 25°C unless otherwise noted; Electricals apply in both directions)

Characteristic		Symbol	Min	Typ	Max	Unit
Peak On–State Voltage (I_{TM} = ±11 A Peak, Pulse Width ≤2 ms, Duty Cycle ≤2%)		V_{TM}	–	1.2	1.65	V
Gate Trigger Current (Continuous dc) (V_D = 12 V, R_L = 100 Ohms)	MT2(+), G(+)	I_{GT}	–	12	50	mA
	MT2(+), G(–)		–	12	50	
	MT2(–), G(–)		–	20	50	
	MT2(–), G(+)		–	35	75	
Gate Trigger Voltage (Continuous dc) (V_D = 12 V, R_L = 100 Ω)	MT2(+), G(+)	V_{GT}	–	0.9	2.0	V
	MT2(+), G(–)		–	0.9	2.0	
	MT2(–), G(–)		–	1.1	2.0	
	MT2(–), G(+)		–	1.4	2.5	
Gate Non–Trigger Voltage (Continuous DC), (V_D = 12 V, T_C = 110°C, R_L = 100 Ω) All Four Quadrants		V_{GD}	0.2	–	–	V
Holding Current (V_D = 12 V_{dc}, Gate Open, Initiating Current = ±200 mA))		I_H	–	6.0	50	mA
Turn-On Time (Rated V_{DRM}, I_{TM} = 11 A) (I_{GT} = 120 mA, Rise Time = 0.1 s, Pulse Width = 2 s)		t_{gt}	–	1.5	–	µs

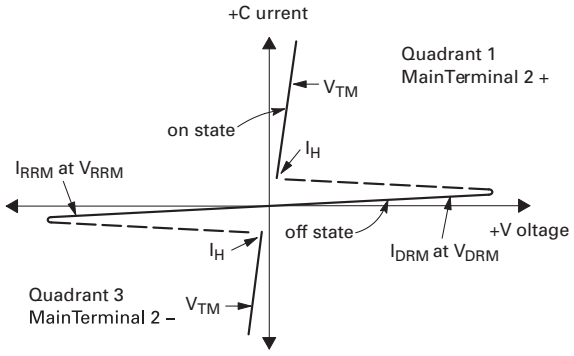
Dynamic Characteristics

Characteristic	Symbol	Min	Typ	Max	Unit
Critical Rate of Rise of Commutation Voltage (V_D = Rated V_{DRM}, I_{TM} = 14 A, Commutating di/dt = 5.0 A/ms, Gate Unenergized, T_C = 70°C)	(di/dt)c	–	5.0	–	A/ms
Critical Rate of Rise of Off-State Voltage (V_D = Rated V_{DRM}, Exponential Waveform, Gate Open, T_C = ±70°C)	dv/dt	–	100	–	V/µs

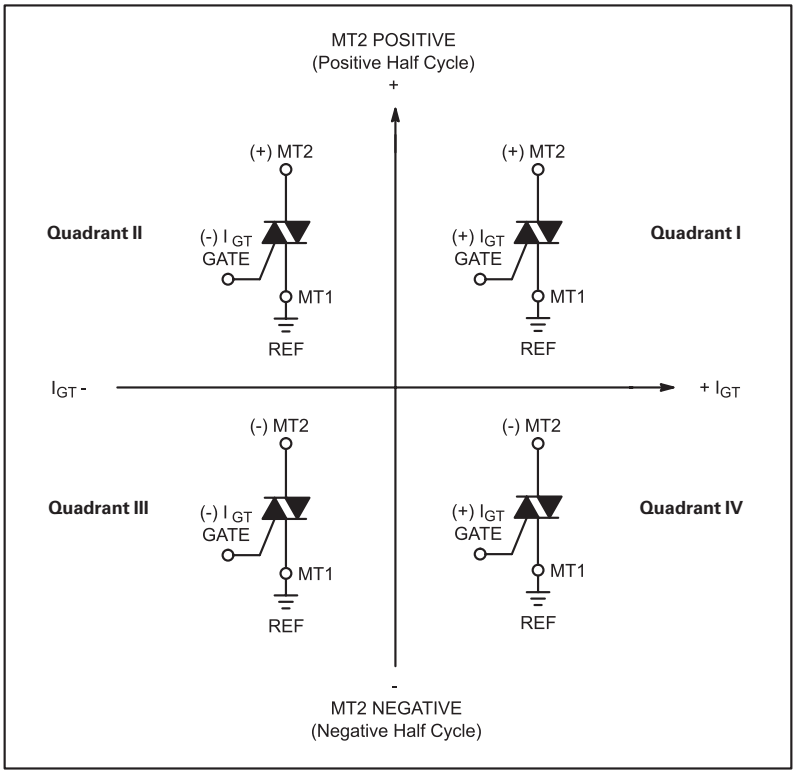
Revised: 08/30/17

Voltage Current Characteristic of SCR

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I_{DRM}	Peak Forward Blocking Current
V_{RRM}	Peak Repetitive Reverse Off State Voltage
I_{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
I_H	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in–phase signals (using standard AC lines) quadrants I and III are used.

Revised: 08/30/17

Figure 1. Current Derating

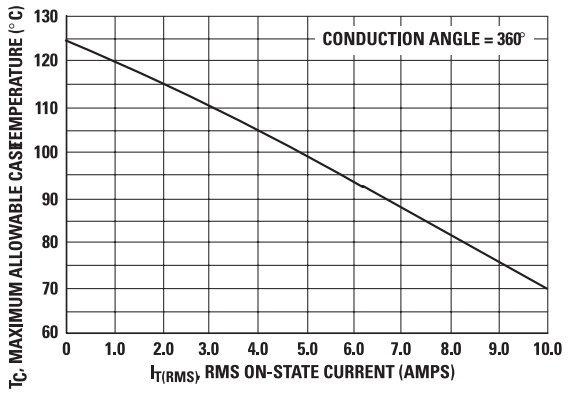


Figure 2. Power Dissipation

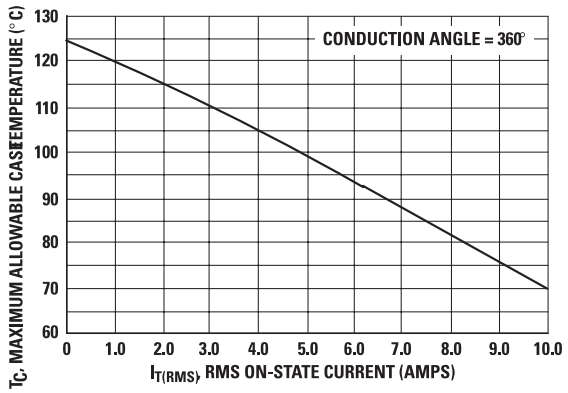


Figure 3. Maximum On–State Characteristics

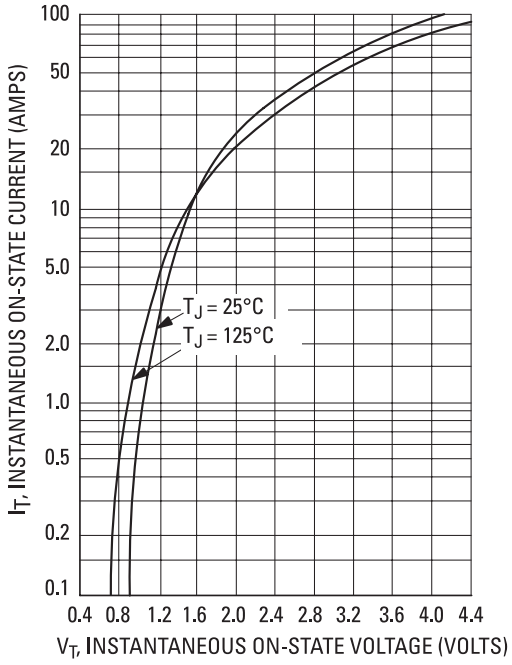


Figure 4. Maximum Non–Repetitive Surge Current

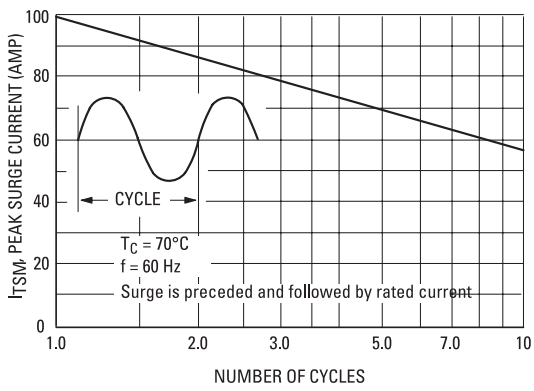
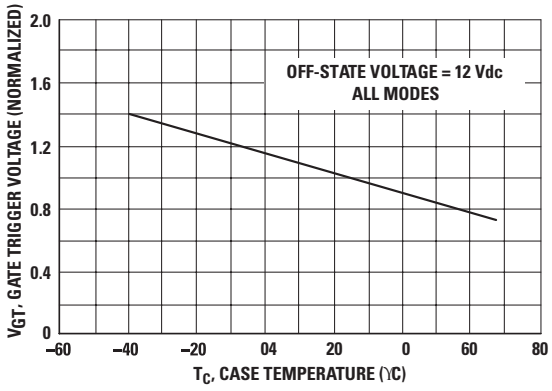


Figure 5. Typical Gate Trigger Voltage



Revised: 08/30/17

Figure 6. Typical Gate Trigger Current

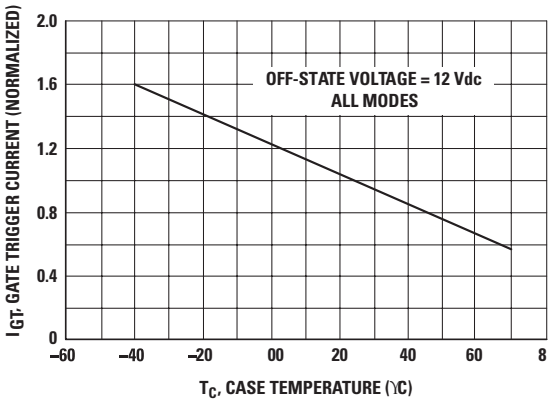


Figure 7. Typical Holding Current

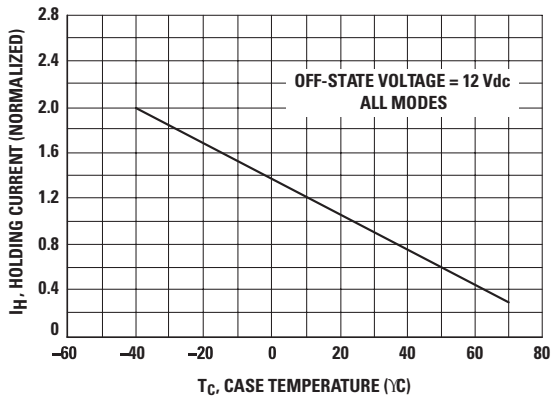
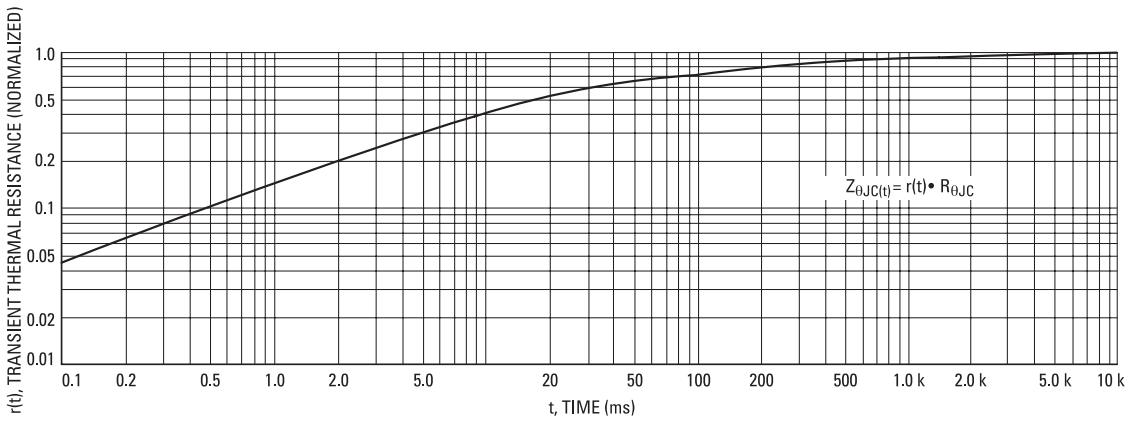


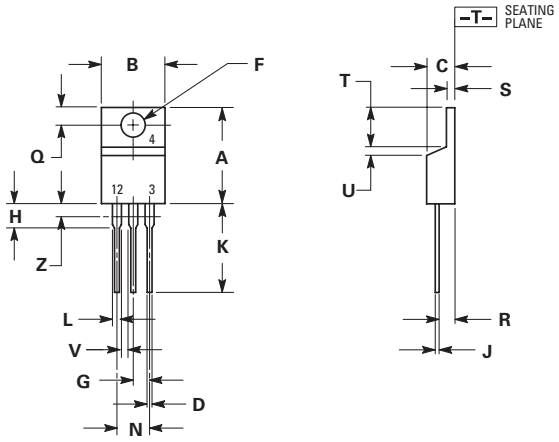
Figure 8. Thermal Response



Thyristors

Surface Mount – 250V > MAC3030-8

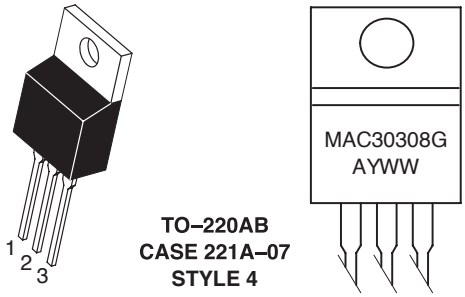
Dimensions



Dim	Inches		Millimeters	
	Min	Max	Min	Max
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.014	0.022	0.36	0.55
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	---	1.15	---
Z	---	0.080	---	2.04

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

Part Marking System



TO–220AB
CASE 221A–07
STYLE 4

MAC3030–8 = Standard Device Code
MAC30308G = Pb–Free Device Code
A= Assembly Location
Y= Year
WW = Work Week

Pin Assignment

1	Main Terminal 1
2	Main Terminal 2
3	Gate
4	Main Terminal 2

Ordering Information

Device	Package	Shipping
MAC3030-8	TO-220AB	500 Units/ Bulk
MAC3030-8G	TO-220AB (Pb-Free)	500 Units/ Bulk